



SBRT2U45LP

2A TrenchSBR TRENCH SUPER BARRIER RECTIFIER

Product Summary

V _{RRM} (V)	I _O (A)	V _{F(MAX)} (V) @ +25°C	I _{R(MAX)} (mA) @ +25°C
45	2	0.55	0.1

Description and Applications

The SBRT2U45LP provides very low V_F and excellent reverse leakage stability at high temperatures. It is ideal for use as bypass diode and rectifier, freewheel diode or blocking diode in applications such as:

- Solar Panels
- Blocking Diode
- Bypass Diode
- Boost Diode
- Recirculating Diode

Features and Benefits

- Patented TrenchSBR Technology Provides Superior Avalanche Capability Versus Schottky Diodes, Ensuring More Rugged and Reliable End Applications
- Reduced Ultra-low Forward Voltage Drop (V_F); Better Efficiency and Cooler Operation
- Reduced High Temperature Reverse Leakage; Increased Reliability Against Thermal Runaway Failure in High Temperature Operation
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

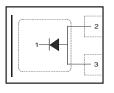
- Case: X1-DFN1411-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Polarity: See Below
- Weight: 2.35 mg (Approximate)

X1-DFN1411-3



Top View





Top View Internal Schematic

Ordering Information (Note 4)

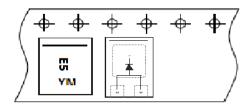
Part Number	Case	Packaging
SBRT2U45LP-7	X1-DFN1411-3	3000/Tape & Reel

Bottom View

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information





E5 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C = 2015) M = Month (ex: 6 = June) Bar = Cathode

Date Code Key

Year	2014	20)15	2016	2017	20	18	2019	2020	20	21	2022
Code	В	(С	D	Е		F	G	Н		I	J
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	45	>
Average Rectified Output Current	lo	2	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	25	А

Thermal Characteristics

Characteristic			Value	Unit	
Typical Thermal Resistance Junction to Case (Note 5)		$R_{\theta JC}$	25	°C/W	
Typical Thermal Resistance Junction to Ambient (Note 5)		$R_{\theta JA}$	100	°C/W	
	V _R ≤ 80% V _{RRM}		-55 to +150		
Operating Temperature Range	V _R ≤ 50% V _{RRM}	T_J	≤ +175	°C	
	DC Forward Mode (Note 7)		≤ + 200		
Storage Temperature Range		T _{STG}	-55 to +150	°C	

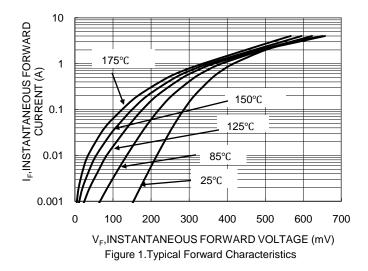
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

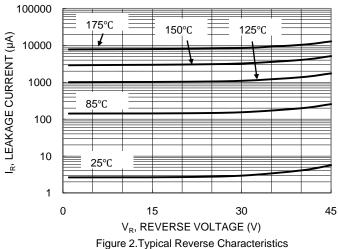
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Forward Voltage Drop (Note 6)	V _F	_	_	0.55	V	$I_F = 2A$, $T_J = +25$ °C
Leakage Current (Note 6)	I _R		_ 2	100 —	' <u>.</u>	$V_R = 45V, T_J = +25$ °C $V_R = 45V, T_J = +125$ °C

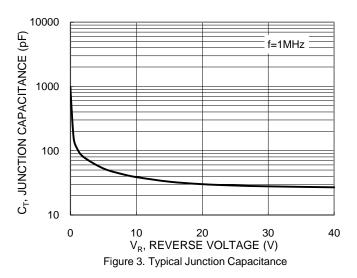
Notes:

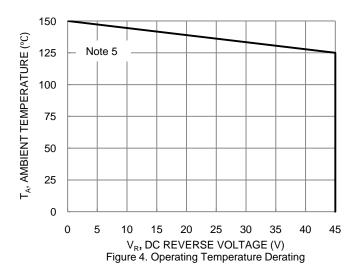
- 5. Device mounted on FR-4 PCB pad layout 1inch 2oz copper.6. Short duration pulse test used to minimize self-heating effect.7. Maximum junction temperature guaranteed for 2 hours.

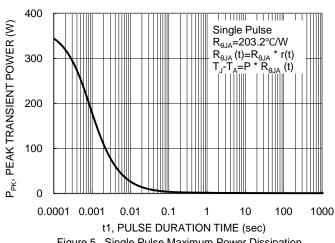












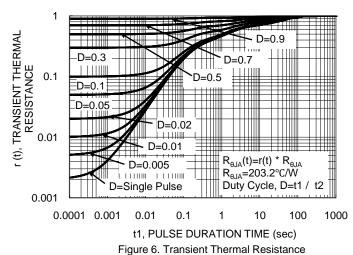
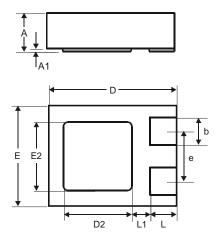


Figure 5. Single Pulse Maximum Power Dissipation



Package Outline Dimensions

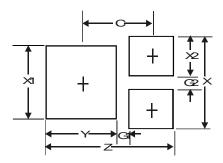
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	X1-DFN1411-3							
Dim	Min Max Typ							
Α	0.47	0.53	0.50					
A1	0.00	0.05	0.02					
b	0.25	0.35	0.30					
D	1.35	1.475	1.40					
D2	0.65	0.85	0.75					
Е	1.05	1.175	1.10					
E2	0.65	0.85	0.75					
е	_	_	0.55					
L	0.225	0.325	0.275					
L1			0.20					
All Dimensions in mm								

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	1.38
G1	0.15
G2	0.15
Х	0.95
X1	0.75
X2	0.40
Y	0.75
С	0.76



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